



PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

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| Applicant : | Stephen P. Vernon et al. | Docket No. : | IL-11011 |
| Serial No. : | 10 676 876 | Art Unit : | |
| Filed : | September 30, 2003 | Examiner | |
| For : | Direct-Patterned Optical Waveguides on Amorphous Silicon Films | | |

Commissioner for Patents
Alexandria, VA

CERTIFICATE OF MAILING UNDER 37 CFR 1.8(a)

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PATENT

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Applicant : Stephen P. Vernon et al

Docket No. IL-11011

Customer No: 24981

Serial No. : 10 676 876

Art Unit :

Filed : September 30, 2003

Examiner :

For : Direct-Patterned Optical Waveguides on Amorphous
Silicon Films

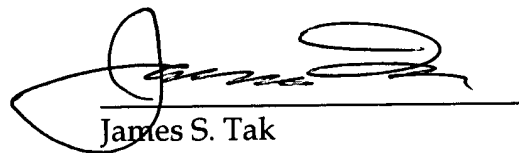
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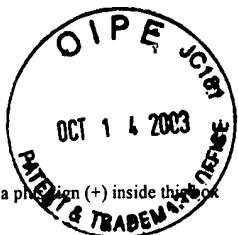
Respectfully submitted,



James S. Tak
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Dated: 10-7-03

Enclosure:
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| | | Application Number | |
| | | Filing Date | |
| | | First Named Inventor | |
| | | Group Art Unit | |
| Examiner Name | | | |
| Attorney Docket Number | | IL-11011 | |
| Sheet | 1 | of | 2 |

U.S. PATENT DOCUMENTS

| Examiner Initials* | Cite No. ¹ | U.S. Patent Document Number | Kind Code ² (if known) | Name of Patentee or Applicant of Cited Document | Date of Publication of Cited Document MM-DD-YYYY | Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear |
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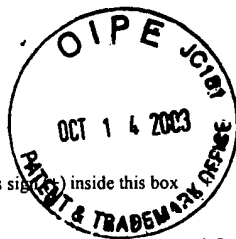
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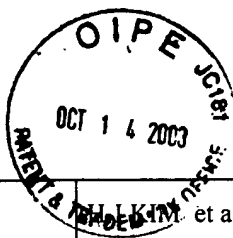
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| | | Application Number | |
| | | Filing Date 9/30/2003 | |
| | | First Named Inventor Stephen P. Vernon | |
| | | Group Art Unit | |
| Examiner Name | | | |
| Sheet 2 | IL- 2 | Attorney Docket Number IL-11011 | |
| OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS | | | |
| Examiner Initials* | Cite No. ¹ | Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published. | |
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